

## 8.0kV 5mA HIGH VOLTAGE DIODES

ZB08 is high reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

**■ Features**

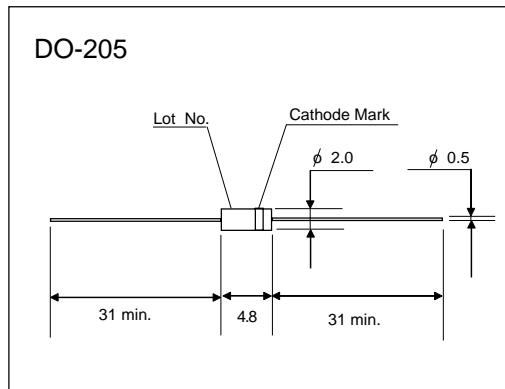
- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage

**■ Applications**

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

**■ Maximum Ratings and Characteristics**

- Absolute Maximum Ratings

**■ Outline Drawings : mm****■ Cathode Mark**

Type	Mark
ZB08	

Items	Symbols	Condition	ZB08	Units
Repetitive Peak Reverse Voltage	$V_{RRM}$		8.0	kV
Average Output Current	$I_o$	Ta=25°C, Resistive Load	5.0	mA <sub>peak</sub>
Surge Current	$I_{FSM}$		0.5	A <sub>peak</sub>
Junction Temperature	$T_j$		120	°C
Allowable Operation Case Temperature	$T_c$		120	°C
Storage Temperature	$T_{stg}$		-40 to +120	°C

- Electrical Characteristics (Ta=25°C Unless otherwise specified )

Items	Symbols	Conditions	ZB08	Units
Maximum Forward Voltage Drop	$V_F$	at 25°C, $I_F = I_{F(AV)}$	25	V
Maximum Reverse Current	IR1	at 25°C, $V_R = V_{RRM}$	2.0	uA
	IR2	at 100°C, $V_R = V_{RRM}$	5.0	uA
Maximum Reverse Recovery Time	$T_{rr}$	at 25°C	100	nS
Junction Capacitance	$C_j$	at 25°C, $V_R=0V, f=1MHz$	1.0	pF